NSN 5961-01-080-1494

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Inclosure Material:

Metal

Overall Length:

Between 0.185 inches and 0.215 inches

Overall Diameter:

Between 0.270 inches and 0.290 inches

Mounting Facility Quantity:

1

Internal Configuration:

Junction contact

Mounting Method:

Threaded stud

Features Provided:

Hermetically sealed case

Thread Size:

0.164 inches

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

45.0 collector to base voltage/static/emitter open and 45.0 collector to emitter reverse voltage and 3.5 emitter to base voltage, static, collector open

Current Rating Per Characteristic:

0.35 amperes source cutoff current

Power Rating Per Characteristic:

7.2 watts small-signal input power, common-collector preset

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

Special Features:

Junction pattern arrangement: npn

Test Data Document:

45413-134764 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Thread Series Designator:

Unf

Terminal Type And Quantity:

4 ribbon

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

A110a0